GTR Module

Silicon N Channel IGBT

High Power Switching Applications Motor Control Applications

Features

High input impedance

• High speed:

 $t_f = 1.0 \mu s \text{ (Max.)}$

 $t_{rr} = 0.5 \mu s \text{ (Max.)}$

Low saturation:

V_{CE (sat)}= 2.7V (Max.)

· Enhancement mode

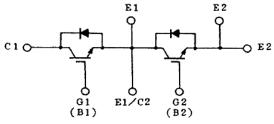
· The electrodes are isolated from case

· Includes a complete half bridge card in one package

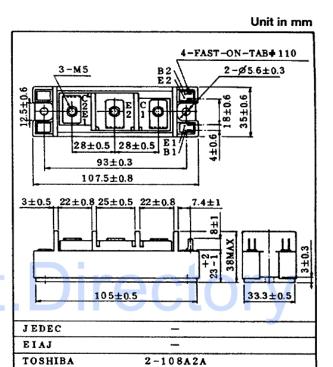
Maximum Ratings (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Emitter Voltage		V _{CES}	1200	٧	
Gate-Emitter Voltage		V _{GES}	± 20	٧	
Collector Current	DC	lc	75	А	
Compositor Curronic	1ms	I _{CP}	150		
Forward Current	DC	IF	75	Α	
T GIMAIG GUITOIR	1ms	I _{FM}	150		
Collector Power Dissipation (Tc = 25°C)		Pc	600	w	
Junction Temperature		Tj	150	ů	
Storage Temperature Range		T _{stg}	-40 ~ 125	°C	
Isolation Voltage		V _{Isol}	2500 (AC 1 min.)	٧	
Screw Torque (Terminal/Mounting)		— 3/3		N¥m	

Equivalent Circuit



■ 9097250 0021983 **0**58 ■

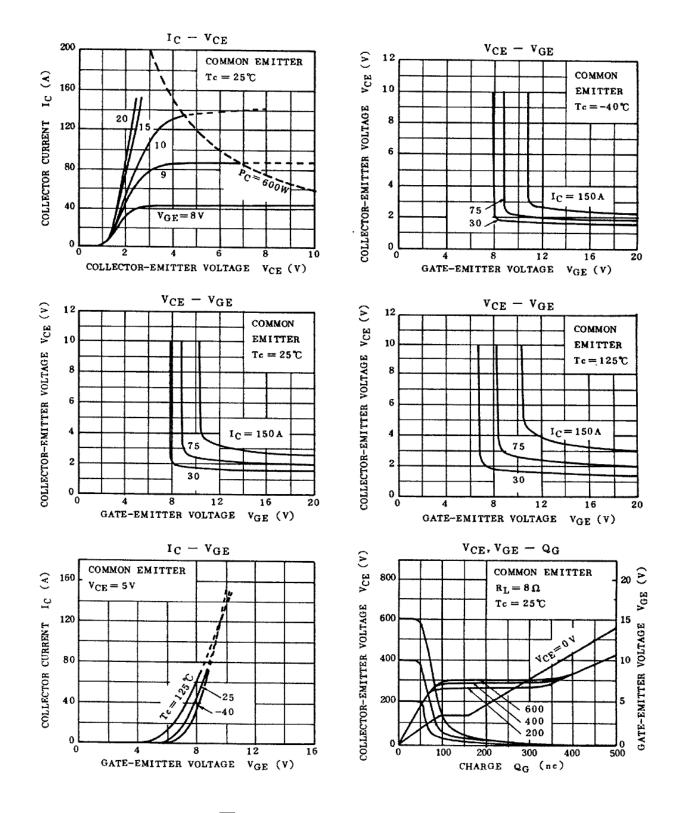


Weight: 240g

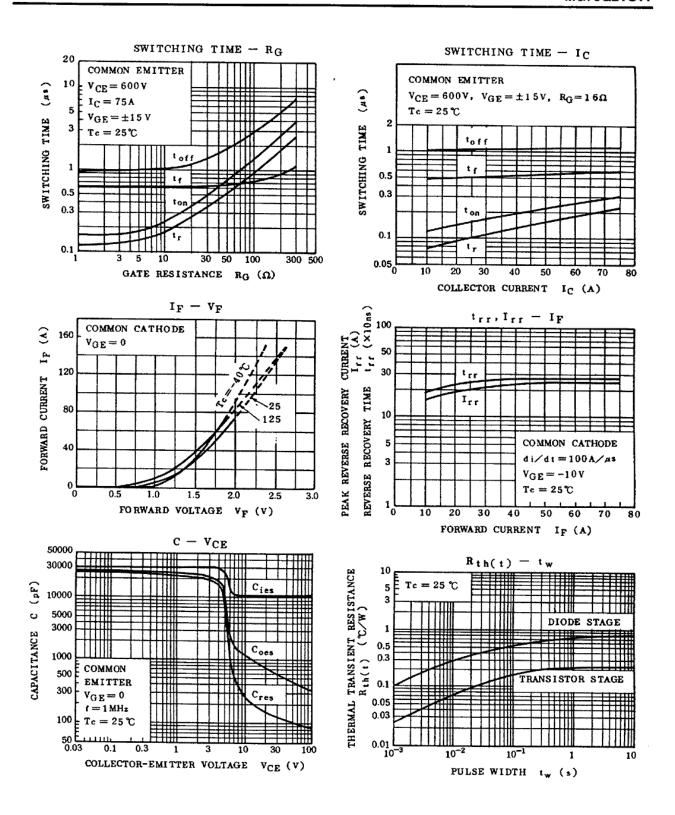
Electrical Characteristics (Ta = 25°C)

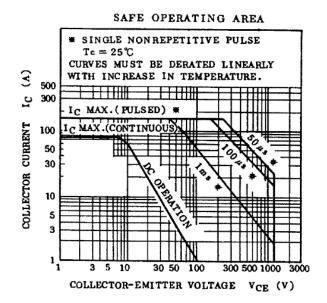
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage Current		IGES	$V_{GE} = \pm 20V, V_{CE} = 0$	_	_	± 500	nA
Collector Cut-off Current		ICES	V _{CE} = 1200V, V _{GE} = 0	_	_	1.0	mA
Collector-Emitter Voltage		V _{CES}	I _C ≤ 1mA, V _{GE} = 0 Note 1	1200	_		٧
Gate-Emitter Cut-off Voltage		V _{GE (OFF)}	I _C = 75mA, V _{CE} = 5V	3.0	_	6.0	٧
Collector-Emitter Saturation Voltage		V _{CE (sat)}	I _C = 75A, V _{GE} = 15V	_	2.2	2.7	٧
Input Capacitance		C _{ies}	V _{CE} = 10V, V _{GE} = 0, f = 1MHz	_	10000		pF
Switching Time	Rise Time	t _r	15V 0 16Ω -15V 600 V	_	0.3	0.6	μs
	Turn-on Time	t _{on}			0.4	0.8	
	Fall Time	t _f			0.6	1.0	
	Turn-off Time	t _{off}		_	1.2	1.8	
Forward Voltage		V _F	$I_F = 75A$, $V_{GE} = 0$		2.0	3.0	٧
Reverse Recovery Time		t _{rr}	l _F = 75A, V _{GE} = -10V di/dt = 100A/μs	_	0.25	0.5	μs
Thermal Resistance		В	Transistor	_	_	0.208	•c/w
		R _{th (j - c)}	Diode	_	_	0.8	

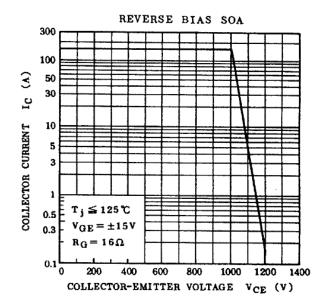
Note 1: Do not apply the over rating voltage.



■ 9097250 0021985 920 **■**







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